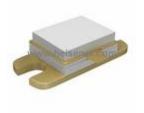




MX0912B251Y,114 Information



For Reference Only

Part Number MX0912B251Y,114 **Manufacturer** Ampleon USA Inc.

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - RF

Description TRANSISTOR POWER NPN SOT439A

Package SOT-439A

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









MX0912B251Y,114 Specifications

Manufacturer Part Number	MX0912B251Y,114
Manufacturer	Ampleon USA Inc.
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	SOT-439A
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	20V
Frequency - Transition	1.215GHz
Noise Figure (dB Typ @ f)	-
Gain	7.4dB
Power - Max	690W
DC Current Gain (hFE) (Min) @ Ic, Vce	-
Current - Collector (Ic) (Max)	15A
Operating Temperature	200°C (TJ)
Mounting Type	Surface Mount
Package / Case	SOT-439A
Supplier Device Package	CDFM2
	Report errors?

MX0912B251Y,114 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MX0912B251Y,114 Payment Methods



















MX0912B251Y,114 Shipping Methods













If you have any question about MX0912B251Y,114, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com